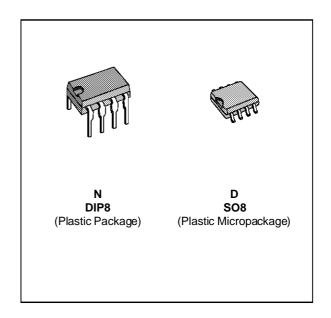


MC4558

WIDE BANDWIDTH DUAL BIPOLAR OPERATIONAL AMPLIFIERS

- INTERNALLY COMPENSATED
- SHORT-CIRCUIT PROTECTION
- GAIN AND PHASE MATCH BETWEEN AMPLIFIERS
- LOW POWER CONSUMPTION
- PIN TO PIN COMPATIBLE WITH MC1458/LM358
- GAIN BANDWIDTH PRODUCT (at 100kHz)
 5.5MHz



DESCRIPTION

The MC4558 is a high performance monolithic dual operational amplifier.

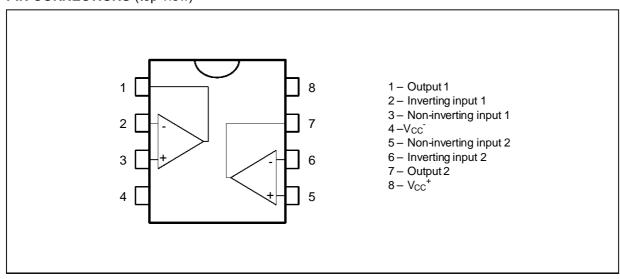
The circuit combines all the outstanding features of the MC1458 and, in addition, possesses three times the unity gain bandwidth of the industry standard.

ORDER CODES

Part	Temperature	Pakcage			
Number	Range	N	D		
MC4558C	0°C, +70°C	•	•		
MC4558I -40°C, +105°C		•	•		
Farancia MO45500N					

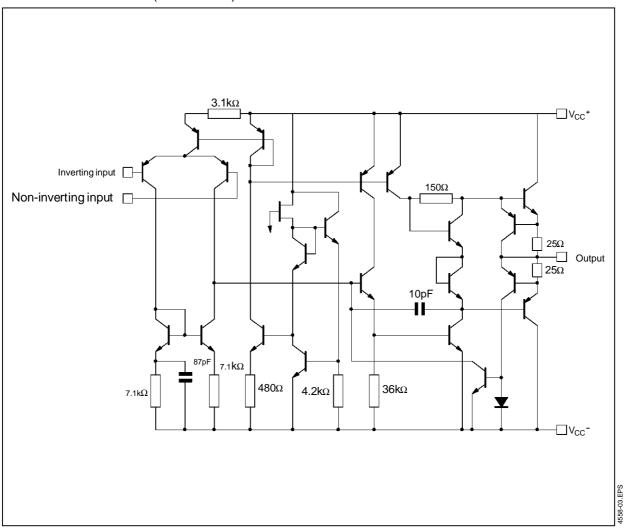
Example: MC4558CN

PIN CONNECTIONS (top view)



April 1995 1/6

SCHEMATIC DIAGRAM (1/2 MC4558)



ABSOLUTE MAXIMUM RATINGS

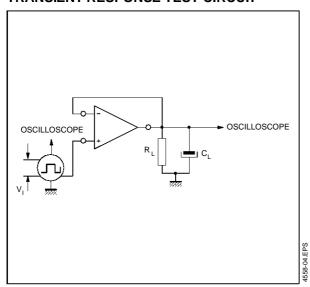
Symbol	Parameter	MC4558I	MC4558C	Unit
Vcc	Supply Voltage	±22 ±22		V
Vi	Input Voltage	±15	±15	V
V _{id}	Differential Input Voltage	±30	±30	V
P _{tot}	Power Dissipation	680	680	mW
	Output Short-circuit Duration	Infinite		
Toper	Operating Free-air Temperature Range	-40 to +105	0 to +70	°C
T _{stg}	Storage Temperature Range	-65 to +150	-65 to +150	°C

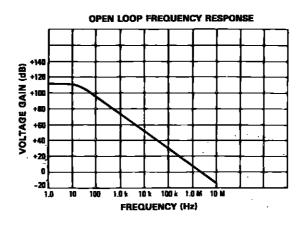
ELECTRICAL CHARACTERISTICS

 $V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

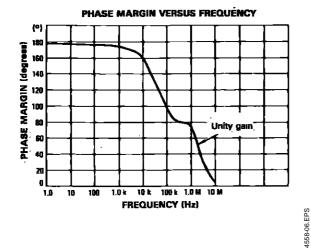
Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input Offset Voltage (R _S \leq 10 k Ω) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max}.$		1	5 6	mV
l _{io}	Input Offset Current $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max}.$		20	100 200	nA
l _{ib}	Input Bias Current $ T_{amb} = 25^{\circ}C $ $ T_{min.} \leq T_{amb} \leq T_{max}. $		50	400 500	nA
A_{vd}	Large Signal Voltage Gain ($V_O = \pm 10V$, $R_L = 2k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	50 25	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}.$	77 77	90		dB
Icc	Supply Current, all Amp, no Load $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$		2.3	4.5 6	mA
V _{icm}	Input Common Mode Voltage Range $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	±12 ±12			V
CMR	Common-mode Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max}$.	70 70	90		dB
Ios	Output Short-circuit Current	10	20	40	mA
Vo	$ \begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = 25^{\circ}C & R_{L} = 10k\Omega \\ R_{L} = 2k\Omega \\ T_{min.} \leq T_{amb} \leq T_{max.} & R_{L} = 10k\Omega \\ R_{L} = 2k\Omega \end{array} $	±12 ±10 ±12 ±10	±14 ±13		٧
SR	Slew Rate $(V_I = \pm 10V, R_L = 2k\Omega, C_L = 100pF, T_{amb} = 25^{\circ}C, unity gain)$	1.5	2.2		V/µs
t _r	Rise Time (V _I = ± 20 mV, R _L = 2 k Ω , C _L = 100 pF, T _{amb} = 25 °C, unity gain)		0.3		μs
Kov	Overshoot $(V_1 = \pm 20 \text{ mV}, R_L = 2k\Omega, C_L = 100 \text{pF}, T_{amb} = 25^{\circ}\text{C}, \text{ unity gain})$		15		%
Ri	Input Resistance	0.3	2		MΩ
Ci	Input Capacitance		1.4		pF
Ro	Output Resistance		75		Ω
В	Unity Gain Bandwidth		2.8		MHz
GBP	Gain Bandwidth Product (V _I = 10mV, R_L = 2k Ω , C_L = 100pF, f = 100kHz, T_{amb} = 25°C)		5.5		MHz
THD	Total Harmonic Distorsion (f = 1kHz, A_v = 20dB, R_L = 2k Ω , V_o = 2V _{pp} , C_L = 100pF, T_{amb} = 25°C)		0.008		%
en	Equivalent Input Noise Voltage (f = 1kHz, $R_s = 100\Omega$)		12		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
V _{O1} /V _{O2}	Channel Separation		120		dB

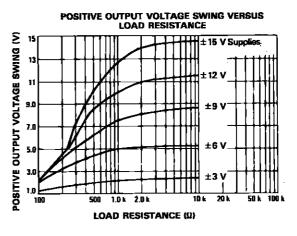
TRANSIENT RESPONSE TEST CIRCUIT



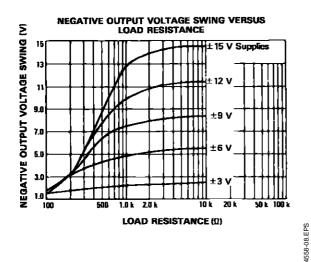


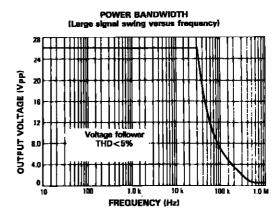
558-05 FPS





4558-07.EPS

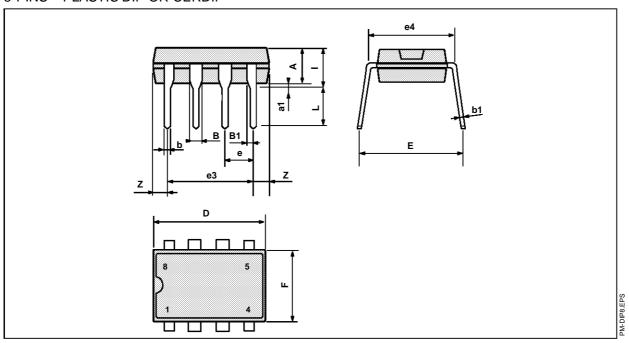




4558-09.EPS

PACKAGE MECHANICAL DATA

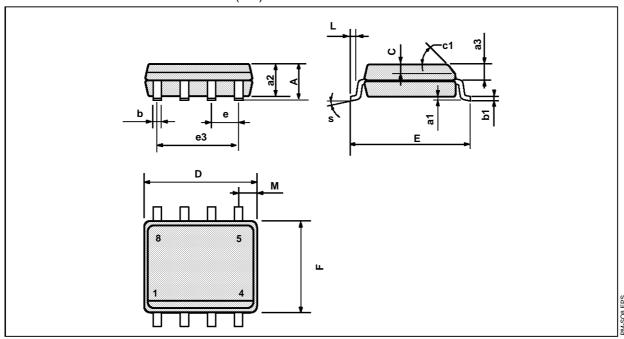
8 PINS - PLASTIC DIP OR CERDIP



Dimensions	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α		3.32			0.131	
a1	0.51			0.020		
В	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
е		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
а3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1	45° (typ.)						
D	4.8		5.0	0.189		0.197	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F	3.8		4.0	0.150		0.157	
L	0.4		1.27	0.016		0.050	
M			0.6			0.024	
S	8° (max.)						

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